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Stocking Distributor

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<u>Vishay Semiconductor/Opto Division</u> TSUS3400

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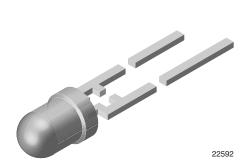


TSUS3400

GREEN

Vishay Semiconductors

Infrared Emitting Diode, 950 nm, GaAs



TSUS3400 is an infrared, 950 nm emitting diode in GaAs

technology, molded in a clear, blue tinted plastic package.

FEATURES

Package type: leadedPackage form: T-1

• Dimensions (in mm): Ø 3

• Peak wavelength: $\lambda_p = 950 \text{ nm}$

· High reliability

• Angle of half intensity: $\varphi = \pm 18^{\circ}$

· Low forward voltage

• Radiant power: 20 mW at I_F = 100 mA

• Suitable for DC and high pulse current operation

• Good spectral matching with Si photodetectors

 Compliant to RoHS Directive 2002/95/EC and in accordance with WEEE 2002/96/EC

Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

Infrared source in photo interrupters, reflective and transmissive sensors

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
TSUS3400	15	± 18	950	800	

Note

DESCRIPTION

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSUS3400	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1		

Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	2	Α	
Power dissipation		P _V	170	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient		R _{thJA}	450	K/W	

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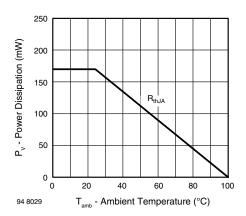
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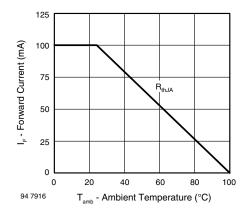


Fig. 2 - Forward Current vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.3	1.7	V
	$I_F = 1.5 \text{ A}, t_p = 100 \mu \text{s}$	V _F		2.2		V
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		- 1.3		mV/K
Reverse current	V _R = 5 V	I _R			100	μΑ
Breakdown voltage	I _R = 100 μA	V _(BR)	5	40		V
Junction capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	C _j		30		pF
B. P. 111 . 11	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	7	15	35	mW/sr
Radiant intensity	$I_F = 1.5 \text{ A}, t_p = 100 \mu \text{s}$	l _e		140		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		20		mW
Temperature coefficient of φ _e	I _F = 20 mA	TKφ _e		- 0.8		%/K
Angle of half intensity		φ		± 18		deg
Peak wavelength	I _F = 100 mA	λ_{p}		950		nm
Spectral bandwidth	I _F = 100 mA	Δλ		50		nm
Temperature coefficient of λ_p	I _F = 100 mA	TKλ _p		0.2		nm/K
Rise time	I _F = 100 mA	t _r		800		ns
	I _F = 1.5 A	t _r		400		ns
Fall time	I _F = 100 mA	t _f		800		ns
	I _F = 1.5 A	t _f		400		ns
Virtual source diameter		d		2.1		mm

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TSUS3400

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

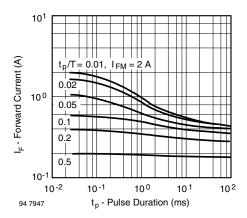


Fig. 3 - Pulse Forward Current vs. Pulse Duration

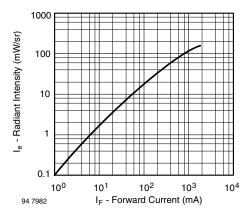


Fig. 6 - Radiant Intensity vs. Forward Current

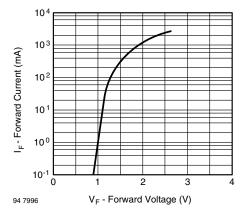


Fig. 4 - Forward Current vs. Forward Voltage

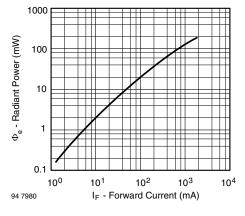


Fig. 7 - Radiant Power vs. Forward Current

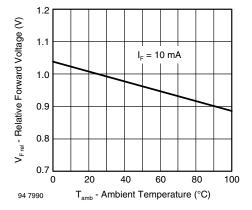


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

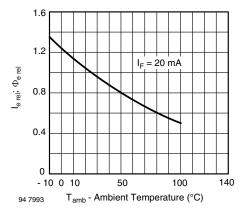


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

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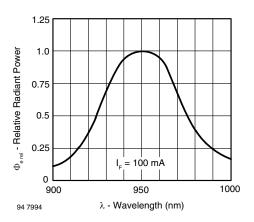


Fig. 9 - Relative Radiant Power vs. Wavelength

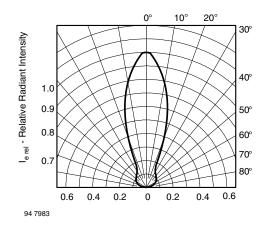
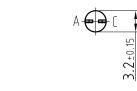
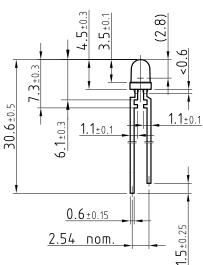


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

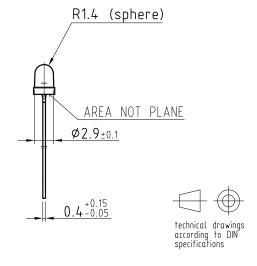
PACKAGE DIMENSIONS in millimeters





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